

UNISONIC TECHNOLOGIES CO., LTD

MGBR10L50 Preliminary DIODE

MOS GATED BARRIER RECTIFIER

■ DESCRIPTION

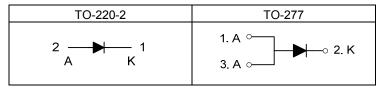
The UTC **MGBR10L50** is a surface mount mos gated barrier rectifier, it uses UTC's advanced technology to provide customers with low forward voltage drop and high current capability, etc.

The UTC **MGBR10L50** suitable for free wheeling, high frequency inverters, polarity protection, and low voltage.

■ FEATURES

- * Low forward voltage drop
- * High current capability
- * High surge capability
- * High efficiency

■ SYMBOL

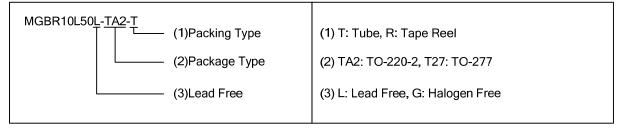


TO-220-2 TO-277

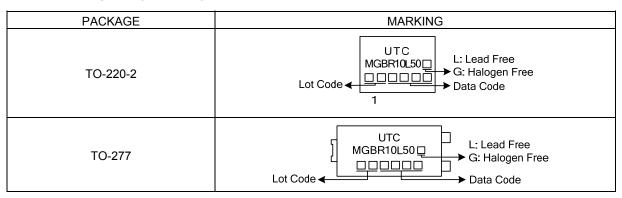
■ ORDERING INFORMATION

Ordering Number		Dookogo	Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
MGBR10L50L-TA2-T	MGBR10L50G-TA2-T	TO-220-2	Α	K	-	Tube	
MGBR10L50L-T27-R	MGBR10L50G-T27-R	TO-277	Α	K	Α	Tape Reel	

Note: Pin Assignment: A: Anode, K: Cathode



■ MARKING INFORMATION



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■ **ABSOLUTE MAXIMUM RATINGS** (T_A=25°C unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

PARAMETER	SYMBOL	RATINGS	UNIT
DC Blocking Voltage (Note 1)	V_{RM}	50	V
Working Peak Reverse Voltage	V_{RWM}	50	V
Peak Repetitive Reverse Voltage	V_{RRM}	50	V
RMS Reverse Voltage	$V_{R(RMS)}$	35	V
Average Rectified Output Current T _C =125°C	Io	10	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	150	Α
Repetitive Peak Avalanche Power (1µs, 25°C)	P _{ARM}	5000	W
Operating Junction Temperature	TJ	-65~+150	°C
Storage Temperature	T _{STG}	-65~+150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL CHARACTERISTICS

PARAMETER		SYMBOL	RATINGS	UNIT	
Junction to Ambient	TO-220-2	0	60	°C/W	
	TO-277	θ_{JA}	73 (Note 3)		
Junction to Case	TO-220-2	0	2.5	°C/M	
	TO-277	θ _{JC}	θ _{JC} 13 (N	13 (Note 3)	°C/W

■ **ELECTRICAL CHARACTERISTICS** (T_A =25°C unless otherwise specified.)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Breakdown Voltage (Note 1)	$V_{(BR)R}$	I _R =0.50mA	50			V
Faculty of National Date	V _{FM}	I _F =10A, T _C =25°C			0.60	V
Forward Voltage Drop		I _F =10A, T _C =125°C			0.55	V
Peak Reverse Current at Rated DC	,	V _R =50V, T _C =25°C			300	μΑ
Blocking Voltage (Note 1)	I _{RM}	V _R =50V, T _C =125°C			25	mA

Notes: 1. Short duration pulse test used to minimize self-heating effect.

- 2. Thermal resistance junction to case mounted on heatsink.
- 3. Mounted on an FR4 PCB, single-sided copper, with 100cm2 copper pad area.

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